TOSHIBA

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# 2SA966

#### Audio Power Amplifier Applications

• Complementary to 2SC2236 and 3-W output applications.

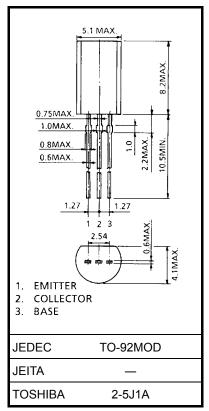
#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-30	V
Collector-emitter voltage	V <sub>CEO</sub>	-30	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ι <sub>C</sub>	-1.5	А
Emitter current	ΙE	1.5	А
Collector power dissipation	PC	900	mW
Junction temperature	Тј	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.36 g (typ.)

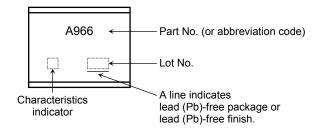
Unit: mm

Electrical Characteristics (Ta = 25°C)

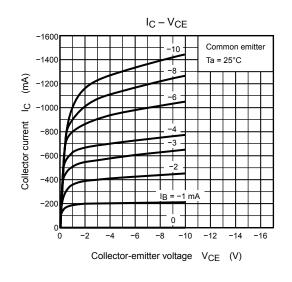
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -30 V, I_{E} = 0$	—	_	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -5 V, I <sub>C</sub> = 0	_	_	-100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-30	_	—	V
Emitter-base breakdown voltage	V (BR) EBO	$I_{E} = -1 \text{ mA}, I_{C} = 0$	-5	_	—	V
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -500 mA	100		320	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = -1.5 A, I <sub>B</sub> = -0.03 A	_		-2.0	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = −2 V, I <sub>C</sub> = −500 mA	_	_	-1.0	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = −2 V, I <sub>C</sub> = −500 mA	_	120	—	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = −10 V, I <sub>E</sub> = 0, f = 1 MHz	_	40	_	pF

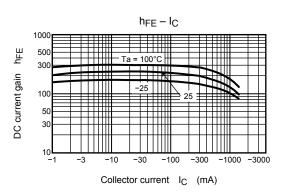
Note: h<sub>FE</sub> classification O: 100 to 200, Y: 160 to 320

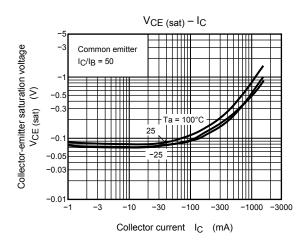
## Marking

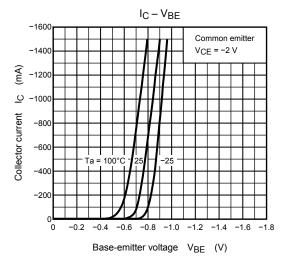


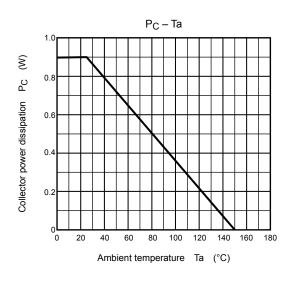
# **TOSHIBA**

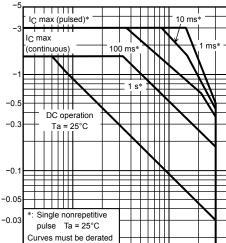












Collector-emitter voltage V<sub>CE</sub> (V)

-3

VCEO max

-30

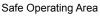
-10

linearly with increase in

-1

temperature.

-0.01 -0.3



E

<u>ں</u>

Collector current

### **RESTRICTIONS ON PRODUCT USE**

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